Preferred Device

# **Silicon Controlled Rectifiers**

## **Reverse Blocking Thyristors**

Designed primarily for half-wave ac control applications, such as motor controls, heating controls and power supply crowbar circuits.

- Glass Passivated Junctions with Center Gate Fire for Greater Parameter Uniformity and Stability
- Small, Rugged, Thermowatt Constructed for Low Thermal Resistance, High Heat Dissipation and Durability
- Blocking Voltage to 800 Volts
- 300 A Surge Current Capability
- Device Marking: Logo, Device Type, e.g., 2N6504, Date Code

#### **MAXIMUM RATINGS** (T<sub>J</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
*Peak Repetitive Off–State Voltage (Note 1.) (Gate Open, Sine Wave 50 to 60 Hz, $T_J = 25$ to $125^{\circ}$ C)	V <sub>DRM,</sub> V <sub>RRM</sub>		Volts
2N6504 2N6505 2N6507 2N6508 2N6509		50 100 400 600 800	
On-State RMS Current (180° Conduction Angles; T <sub>C</sub> = 85°C)	I <sub>T(RMS)</sub>	25	A
Average On-State Current (180° Conduction Angles; $T_C = 85^{\circ}C$ )	I <sub>T(AV)</sub>	16	A
Peak Non-repetitive Surge Current (1/2 Cycle, Sine Wave 60 Hz, $T_J = 100^{\circ}C$ )	I <sub>TSM</sub>	250	A
Forward Peak Gate Power (Pulse Width $\leq$ 1.0 µs, T <sub>C</sub> = 85°C)	P <sub>GM</sub>	20	Watts
Forward Average Gate Power (t = 8.3 ms, $T_C = 85^{\circ}C$ )	P <sub>G(AV)</sub>	0.5	Watts
Forward Peak Gate Current (Pulse Width $\leq$ 1.0 µs, T <sub>C</sub> = 85°C)	I <sub>GM</sub>	2.0	A
Operating Junction Temperature Range	ΤJ	–40 to +125	°C
Storage Temperature Range	T <sub>stg</sub>	–40 to +150	°C

\*Indicates JEDEC Registered Data

 V<sub>DRM</sub> and V<sub>RRM</sub> for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.



## ON Semiconductor\*\*

http://onsemi.com

## SCRs 25 AMPERES RMS 50 thru 800 VOLTS







PIN ASSIGNMENT		
1	Cathode	
2	Anode	
3	Gate	
4	Anode	

#### **ORDERING INFORMATION**

Device	Package	Shipping
2N6504	TO220AB	500/Box
2N6505	TO220AB	500/Box
2N6507	TO220AB	500/Box
2N6508	TO220AB	500/Box
2N6509	TO220AB	500/Box

Preferred devices are recommended choices for future use and best overall value.

#### **\*THERMAL CHARACTERISTICS**

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	1.5	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	TL	260	°C

### **ELECTRICAL CHARACTERISTICS** ( $T_C = 25^{\circ}C$ unless otherwise noted.)

Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
*Peak Repetitive Forward or Reverse Blocking Current (V <sub>AK</sub> = Rated V <sub>DRM</sub> or V <sub>RRM</sub> , Gate Open)	T <sub>J</sub> = 25°C T <sub>J</sub> = 125°C	I <sub>DRM</sub> , I <sub>RRM</sub>			10 2.0	μA mA
ON CHARACTERISTICS				•	•	
*Forward On–State Voltage (Note 2.) (I <sub>TM</sub> = 50 A)		V <sub>TM</sub>	-	-	1.8	Volts
*Gate Trigger Current (Continuous dc) (V <sub>AK</sub> = 12 Vdc, R <sub>L</sub> = 100 Ohms)	$T_C = 25^{\circ}C$ $T_C = -40^{\circ}C$	I <sub>GT</sub>		9.0 —	30 75	mA
*Gate Trigger Voltage (Continuous dc) ( $V_{AK}$ = 12 Vdc, R <sub>L</sub> = 100 Ohms, T <sub>C</sub> = -40°C)		V <sub>GT</sub>	-	1.0	1.5	Volts
Gate Non-Trigger Voltage $(V_{AK} = 12 \text{ Vdc}, R_L = 100 \text{ Ohms}, T_J = 125^{\circ}\text{C})$		V <sub>GD</sub>	0.2	_	-	Volts
*Holding Current (V <sub>AK</sub> = 12 Vdc, Initiating Current = 200 mA,	$T_C = 25^{\circ}C$	Ι <sub>Η</sub>	-	18	40	mA
Gate Open)	$T_C = -40^{\circ}C$		-	-	80	
*Turn-On Time (I <sub>TM</sub> = 25 A, I <sub>GT</sub> = 50 mAdc)		t <sub>gt</sub>	-	1.5	2.0	μs
Turn-Off Time (V <sub>DRM</sub> = rated voltage) ( $I_{TM} = 25 \text{ A}, I_R = 25 \text{ A}$ ) ( $I_{TM} = 25 \text{ A}, I_R = 25 \text{ A}, T_J = 125^{\circ}\text{C}$ )		tq		15 35		μs
DYNAMIC CHARACTERISTICS						
Critical Rate of Rise of Off-State Voltage (Gate Open, Rated V <sub>DRM</sub> , Exponential Waveform)		dv/dt	-	50	_	V/µs

\*Indicates JEDEC Registered Data.

2. Pulse Test: Pulse Width  $\leq 300~\mu s,~\text{Duty}~\text{Cycle} \leq 2\%.$ 

## Voltage Current Characteristic of SCR

Symbol	Parameter
V <sub>DRM</sub>	Peak Repetitive Off State Forward Voltage
I <sub>DRM</sub>	Peak Forward Blocking Current
V <sub>RRM</sub>	Peak Repetitive Off State Reverse Voltage
I <sub>RRM</sub>	Peak Reverse Blocking Current
V <sub>TM</sub>	Peak On State Voltage
Ι <sub>Η</sub>	Holding Current





Figure 1. Average Current Derating

Figure 2. Maximum On–State Power Dissipation



Figure 5. Thermal Response

#### TYPICAL TRIGGER CHARACTERISTICS



Figure 8. Typical Holding Current versus Junction Temperature

#### PACKAGE DIMENSIONS

TO-220AB CASE 221A-07 **ISSUE AA** 





NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIMETER	
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
н	0.110	0.155	2.80	3.93
J	0.014	0.022	0.36	0.55
Κ	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
Ν	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
Т	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045		1.15	
Ζ		0.080		2.04

## <u>Notes</u>

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